

2SK1266

Silicon N-Channel Power F-MOS

■ Features

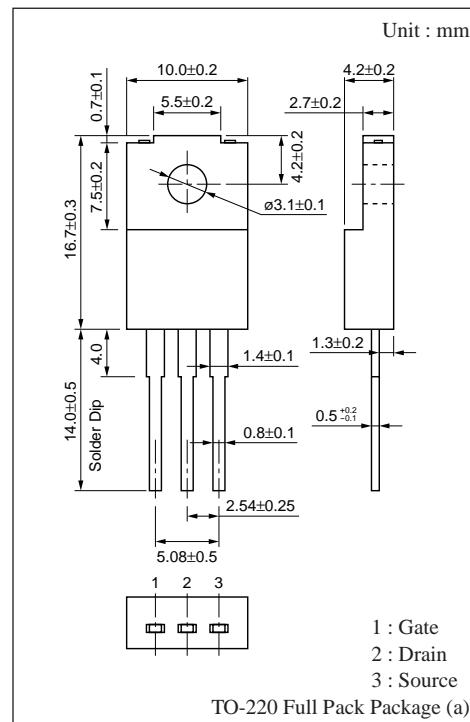
- Low ON-resistance $R_{DS(on)}$: $R_{DS(on)1} = 0.08\Omega(\text{typ})$
- High-speed switching : $t_f = 180\text{ns}(\text{typ})$
- No secondary breakdown
- Low-voltage drive

■ Applications

- DC-DC converter
- Non-contact relay
- Solenoid drive
- Motor drive

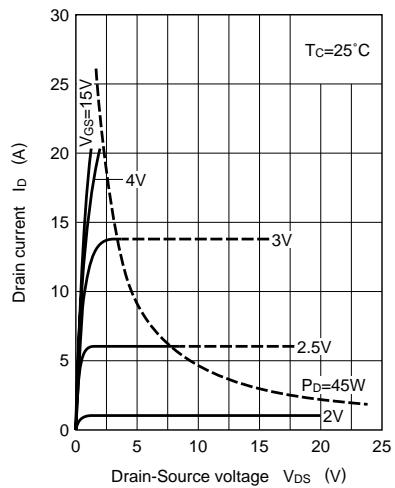
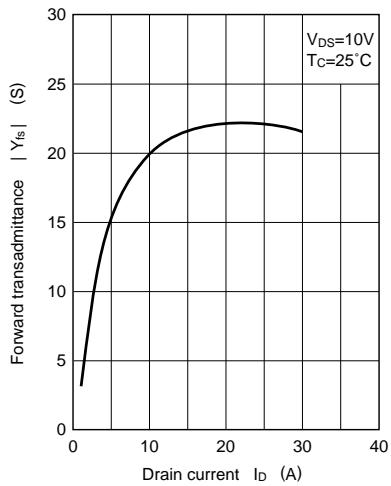
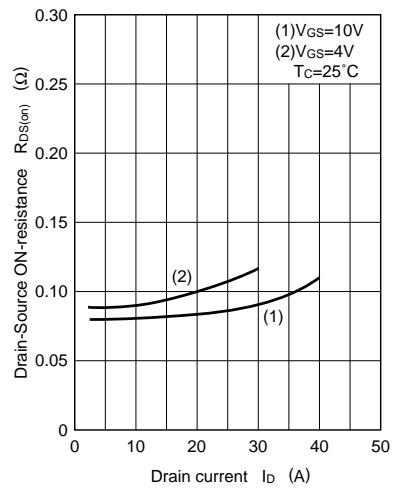
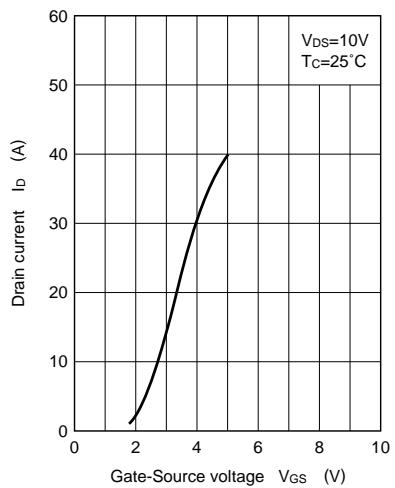
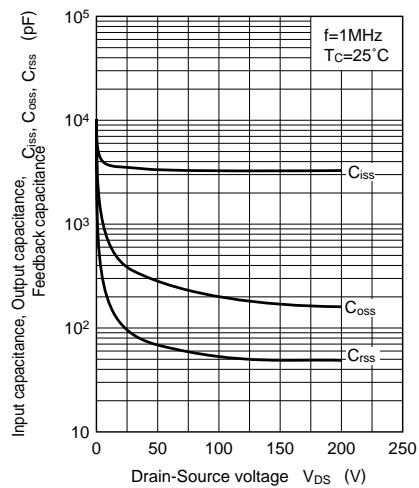
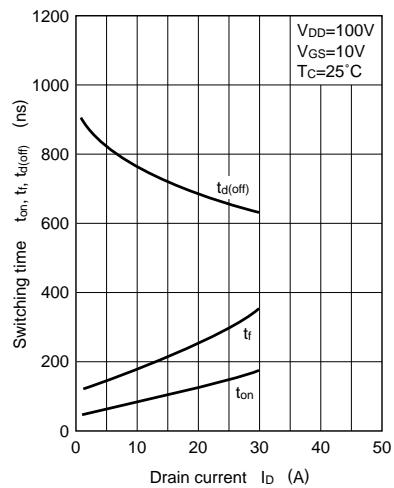
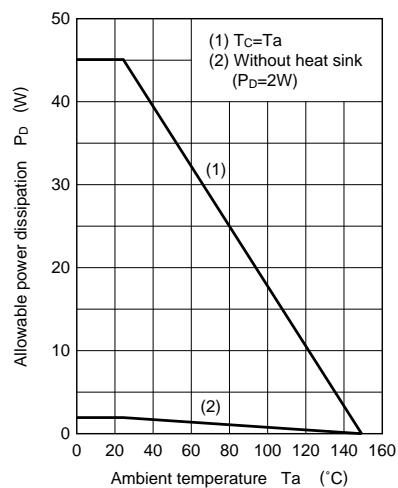
■ Absolute Maximum Ratings ($T_c = 25^\circ\text{C}$)

Parameter	Symbol	Rating	Unit
Drain-Source breakdown voltage	V_{DSS}	150	V
Gate-Source voltage	V_{GSS}	± 20	V
Drain current	DC I_D	± 20	A
	Pulse I_{DP}	± 40	A
Allowable power dissipation	$T_c = 25^\circ\text{C}$	45	W
	$T_a = 25^\circ\text{C}$		
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

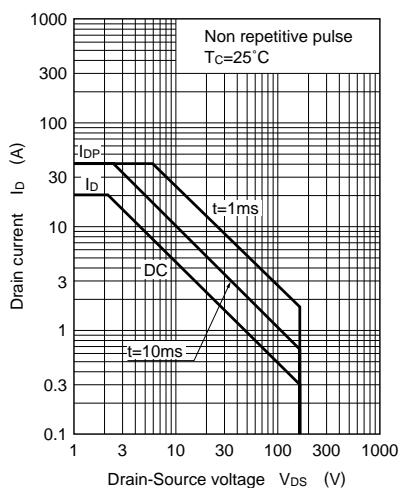


■ Electrical Characteristics ($T_c = 25^\circ\text{C}$)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Drain-Source cut-off current	I_{DSS}	$V_{DS}=130\text{V}, V_{GS}=0$			10	μA
Gate-Source leakage current	I_{GSS}	$V_{GS}=\pm 20\text{V}, V_{DS}=0$			± 1	μA
Drain-Source breakdown voltage	V_{DSS}	$I_D=1\text{mA}, V_{GS}=0$	150			V
Gate threshold voltage	V_{th}	$V_{DS}=10\text{V}, I_D=1\text{mA}$	1		2.5	V
Drain-Source ON-resistance	$R_{DS(on) 1}$	$V_{GS}=10\text{V}, I_D=10\text{A}$		0.08	0.12	Ω
	$R_{DS(on) 2}$	$V_{GS}=4\text{V}, I_D=10\text{A}$		0.09	0.135	Ω
Forward transadmittance	$ Y_{fs} $	$V_{DS}=10\text{V}, I_D=10\text{A}$	10	20		S
Input capacitance	C_{iss}	$V_{DS}=10\text{V}, V_{GS}=0, f=1\text{MHz}$		3450		pF
Output capacitance	C_{oss}			600		pF
Feedback capacitance	C_{rss}			150		pF
Turn-on time	t_{on}	$V_{GS}=10\text{V}, I_D=10\text{A}$ $V_{DD} \approx 100\text{V}, R_L=10\Omega$		90		ns
Fall time	t_f			180		ns
Turn-off time (delay time)	$t_{d(off)}$			770		ns

$I_D - V_{DS}$  $|Y_{fs}| - I_D$  $R_{DS(on)} - I_D$  $I_D - V_{GS}$  $C_{iss}, C_{oss}, C_{rss} - V_{DS}$  $t_{on}, t_f, t_d(\text{off}) - I_D$  $P_D - Ta$ 

Area of safe operation (ASO)

 $R_{DS(on)} - I_D$ 